Schottky barrier single diode in small SOD123F package 25 July 2012 Product data sheet

# 1. Product profile

### 1.1 General description

Planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOD123F small and flat lead Surface-Mounted Device (SMD) plastic package.

### **1.2 Features and benefits**

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Inverse-polarity protection

# 1.4 Quick reference data

| Table 1. C     | Quick reference data |  |     |     |     |      |
|----------------|----------------------|--|-----|-----|-----|------|
| Symbol         | Parameter            | Conditions   | Min | Тур | Мах | Unit |
| l <sub>F</sub> | forward current      |  | -   | -   | 200 | mA   |
| V <sub>R</sub> | reverse voltage      |  | -   | -   | 30  | V    |
| V <sub>F</sub> | forward voltage      | I <sub>F</sub> = 10 mA; pulsed; t <sub>p</sub> ≤ 300 μs;<br>$\delta \le 0.02$ ; T <sub>amb</sub> = 25 °C | -   | -   | 400 | mV   |

# 2. Pinning information

| Table 2. | Pinning | information |                    |                |
|----------|---------|-------------|--------------------|----------------|
| Pin      | Symbol  | Description | Simplified outline | Graphic symbol |
| 1        | К       | cathode[1]  |                    | K 🛃 A          |
| 2        | А       | anode       |                    | aaa-003679     |
|          |         |             | SOD123F            |                |

[1] The marking bar indicates the cathode.





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#### **Ordering information** 3.

| Table 3. Ordering in | formation |  |         |
|----------------------|-----------|--|---------|
| Type number          | Package   |  |         |
|                      | Name      | Description                              | Version |
| BAT54H               | SOD123F   | plastic surface-mounted package; 2 leads | SOD123F |

#### Marking 4.

| Table 4.   Marking codes |              |
|--------------------------|--------------|
| Type number              | Marking code |
| BAT54H                   | AG           |

#### 5. **Limiting values**

#### Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                           | Conditions  |     | Min | Max | Unit |
|------------------|-------------------------------------|---|-----|-----|-----|------|
| V <sub>R</sub>   | reverse voltage                     |   |     | -   | 30  | V    |
| l <sub>F</sub>   | forward current                     |   |     | -   | 200 | mA   |
| I <sub>FRM</sub> | repetitive peak forward current     | t <sub>p</sub> ≤ 1 s; δ ≤ 0.5                             |     | -   | 300 | mA   |
| I <sub>FSM</sub> | non-repetitive peak forward current | $t_p \le 10 \text{ ms; } T_{j(init)} = 25 ^\circ\text{C}$ |     | -   | 600 | mA   |
| P <sub>tot</sub> | total power dissipation             | T <sub>amb</sub> = 25 °C                                  | [1] | -   | 375 | mW   |
| Tj               | junction temperature                |   |     | -   | 125 | °C   |
| T <sub>amb</sub> | ambient temperature                 |   |     | -65 | 125 | °C   |
| T <sub>stg</sub> | storage temperature                 |   |     | -65 | 150 | °C   |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

#### **Thermal characteristics** 6.

| Table 6. The          | ermal characteristics                                  |  |     |     |       |                |                 |
|-----------------------|--|--|-----|-----|-------|----------------|-----------------|
| Symbol                | Parameter  | Conditions   |     | Min | Тур   | Max            | Unit            |
| R <sub>th(j-a)</sub>  | thermal resistance<br>from junction to<br>ambient      | in free air  | [1] | -   | -     | 330            | K/W             |
| R <sub>th(j-sp)</sub> | thermal resistance<br>from junction to solder<br>point |  | [2] | -   | -     | 70             | K/W             |
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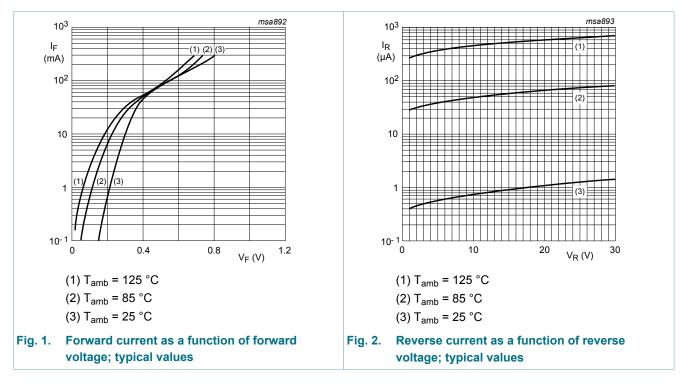
#### Schottky barrier single diode in small SOD123F package

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Soldering point of cathode tab.

# 7. Characteristics

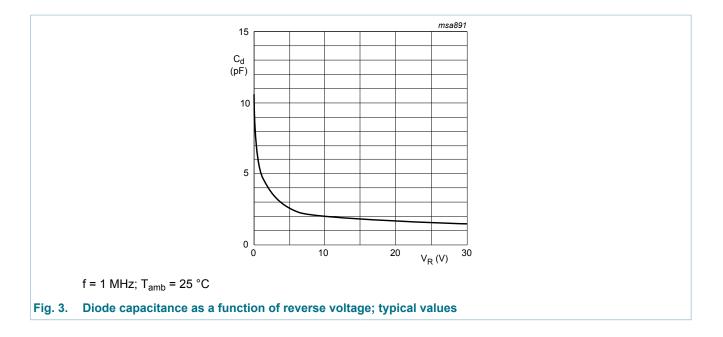
| Table 7. Cha                   | racteristics      |   |     |     |     |      |
|--------------------------------|-------------------|---|-----|-----|-----|------|
| Symbol                         | Parameter         | Conditions  | Min | Тур | Max | Unit |
| V <sub>F</sub> forward voltage | forward voltage   | $I_F$ = 0.1 mA; pulsed; t <sub>p</sub> ≤ 300 μs;<br>δ ≤ 0.02 ; T <sub>amb</sub> = 25 °C                   | -   | -   | 240 | mV   |
|                                |                   | $I_F$ = 1 mA; pulsed; t <sub>p</sub> ≤ 300 μs;<br>δ ≤ 0.02 ; T <sub>amb</sub> = 25 °C                     | -   | -   | 320 | mV   |
|                                |                   | I <sub>F</sub> = 10 mA; pulsed; t <sub>p</sub> ≤ 300 μs;<br>$\delta \le 0.02$ ; T <sub>amb</sub> = 25 °C  | -   | -   | 400 | mV   |
|                                |                   | I <sub>F</sub> = 30 mA; pulsed; t <sub>p</sub> ≤ 300 μs;<br>$\delta \le 0.02$ ; T <sub>amb</sub> = 25 °C  | -   | -   | 500 | mV   |
|                                |                   | I <sub>F</sub> = 100 mA; pulsed; t <sub>p</sub> ≤ 300 μs;<br>$\delta \le 0.02$ ; T <sub>amb</sub> = 25 °C | -   | -   | 800 | mV   |
| I <sub>R</sub>                 | reverse current   | V <sub>R</sub> = 25 V; T <sub>amb</sub> = 25 °C   | -   | -   | 2   | μA   |
| C <sub>d</sub>                 | diode capacitance | f = 1 MHz; $T_{amb}$ = 25 °C; $V_R$ = 1 V   | -   | -   | 10  | pF   |



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# BAT54H

#### Schottky barrier single diode in small SOD123F package

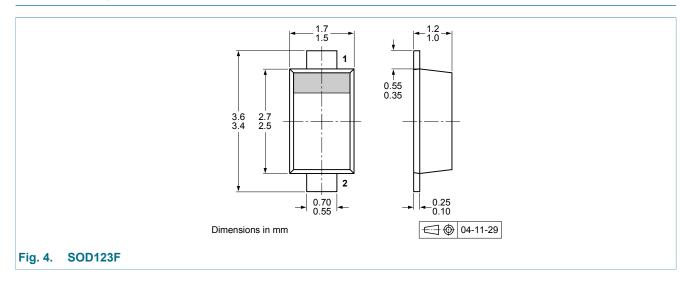


# 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

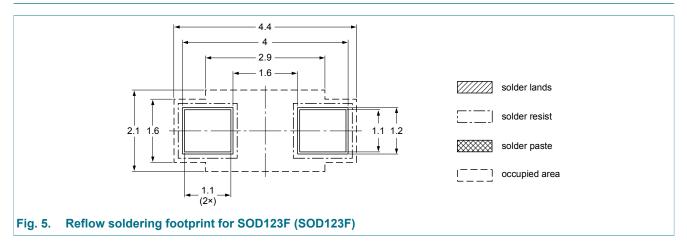
# 9. Package outline



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# **10. Soldering**



# **11. Revision history**

| Table 8. Revision h  | nistory      |                    |               |            |  |
|--|--------------|--------------------|---------------|------------|--|
| Data sheet ID  | Release date | Data sheet status  | Change notice | Supersedes |  |
| BAT54H v.3   | 20120725     | Product data sheet | -             | BAT54H v.2 |  |
| <ul> <li>Modifications:</li> <li>The format of this document has been redesigned to comply with the new identity guideline of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Section "Test information" added</li> </ul> |              |                    |               |            |  |
| BAT54H v.2   | 20100128     | Product data sheet | -             | BAT54H v.1 |  |
| BAT54H v.1   | 20050407     | Product data sheet | -             |            |  |

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# 12. Legal information

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| Document status [1][2]               | Product<br>status [ <u>3]</u> | Definition  |
|--------------------------------------|-------------------------------|---|
| Objective<br>[short] data<br>sheet   | Development                   | This document contains data from<br>the objective specification for product<br>development. |
| Preliminary<br>[short] data<br>sheet | Qualification                 | This document contains data from the preliminary specification.                             |
| Product<br>[short] data<br>sheet     | Production                    | This document contains the product specification.   |

Please consult the most recently issued document before initiating or [1] completing a design.

The term 'short data sheet' is explained in section "Definitions". [2]

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